



## LED - Lamp

## ELD-1720-535

preliminary

27.07.2009

rev. 01

Radiation	Type	Technology	Case
Infrared	MQW	InGaAs/InP	5 mm plastic lens

Description	
	<p>High-power, high-speed infrared LED in standard 5 mm package, housing without standoff leads</p> <p>Note: Special packages with standoff available on request</p>
Applications	
Optical communications, safety equipment, automation	

### Maximum Ratings

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test conditions	Symbol	Value	Unit
Forward current (DC)		$I_F$	100	mA
Peak forward current	$(t_p \leq 50 \mu\text{s}, t_p/T = 1/2)$	$I_{FM}$	200	mA
Power dissipation		$P_D$	150	mW
Operating temperature range		$T_{amb}$	-20 to +80	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	-55 to +100	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5 \text{ s}, 3 \text{ mm from case}$	$T_{sd}$	260	$^{\circ}\text{C}$

### Optical and Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test conditions	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F = 20 \text{ mA}$	$V_F$		0.7		V
Forward voltage*	$I_F = 100 \text{ mA}$	$V_F$		0.9		V
Reverse voltage	$I_R = 100 \mu\text{A}$	$V_R$	5			V
Radiant power	$I_F = 20 \text{ mA}$	$\Phi_e$		1.0		mW
Radiant power*	$I_F = 100 \text{ mA}$	$\Phi_e$		4.0		mW
Peak wavelength	$I_F = 20 \text{ mA}$	$\lambda_p$		1720		nm
Spectral bandwidth at 50%	$I_F = 20 \text{ mA}$	$\Delta\lambda_{0.5}$		130		nm
Viewing angle	$I_F = 20 \text{ mA}$	$\varphi$		30		deg.
Switching time	$I_F = 20 \text{ mA}$	$t_r, t_f$		15		ns

\*for information only